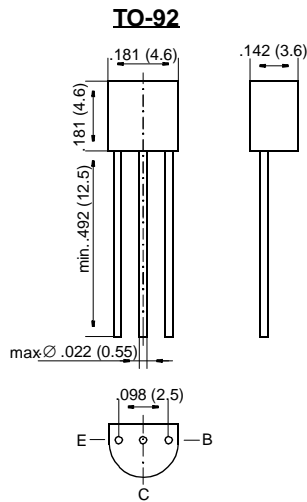


# BF421, BF423

## Small Signal Transistors (PNP)



Dimensions in inches and (millimeters)

### FEATURES

- ◆ PNP Silicon Epitaxial Transistors especially suited for application in class-B video output stages of TV receivers and monitors.
- ◆ As complementary types, the NPN transistors BF420 and BF422 are recommended.



### MECHANICAL DATA

**Case:** TO-92 Plastic Package

**Weight:** approx. 0.18 g

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

		Symbol	Value	Unit
Collector-Base Voltage	<b>BF421</b>	$-V_{CBO}$	300	V
	<b>BF423</b>	$-V_{CBO}$	250	V
Collector-Emitter Voltage	<b>BF423</b>	$-V_{CEO}$	250	V
Collector-Emitter Voltage	<b>BF421</b>	$-V_{CER}$	300	V
Emitter-Base Voltage		$-V_{EBO}$	5	V
Collector Current		$-I_C$	50	mA
Peak Collector Current		$-I_{CM}$	100	mA
Power Dissipation at $T_{amb} = 25\text{ °C}$		$P_{tot}$	830 <sup>1)</sup>	mW
Junction Temperature		$T_j$	150	°C
Storage Temperature Range		$T_S$	-65 to +150	°C

<sup>1)</sup> Valid provided that leads are kept at ambient temperature at a distance of 2 mm from case.

# BF421, BF423

## ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage at $-I_C = 100 \mu\text{A}$ , $I_E = 0$	<b>BF421</b> <b>BF423</b> $-V_{(BR)CBO}$ $-V_{(BR)CBO}$	300 250	– –	– –	V V
Collector-Emitter Breakdown Voltage at $-I_C = 10 \text{ mA}$ , $I_B = 0$	<b>BF423</b> $-V_{(BR)CEO}$	250	–	–	V
Collector-Emitter Breakdown Voltage at $R_{BE} = 2.7 \text{ k}\Omega$ , at $-I_C = 10 \text{ mA}$	<b>BF421</b> $-V_{(BR)CER}$	300	–	–	V
Emitter-Base Breakdown Voltage at $-I_E = 100 \mu\text{A}$ , $I_C = 0$	$-V_{(BR)EBO}$	5	–	–	V
Collector-Base Cutoff Current at $-V_{CB} = 200 \text{ V}$ , $I_E = 0$	$-I_{CBO}$	–	–	10	nA
Collector-Emitter Cutoff Current at $R_{BE} = 2.7 \text{ k}\Omega$ , $-V_{CE} = 250 \text{ V}$ at $R_{BE} = 2.7 \text{ k}\Omega$ , $-V_{CE} = 200 \text{ V}$ , $T_j = 150 \text{ }^\circ\text{C}$	$-I_{CER}$ $-I_{CER}$			50 10	nA $\mu\text{A}$
Collector Saturation Voltage at $-I_C = 30 \text{ mA}$ , $-I_B = 5 \text{ mA}$	$-V_{CEsat}$	–	–	0.8	V
DC Current Gain at $-V_{CE} = 20 \text{ V}$ , $-I_C = 25 \text{ mA}$	$h_{FE}$	50	–	–	–
Gain-Bandwidth Product at $-V_{CE} = 10 \text{ V}$ , $-I_C = 10 \text{ mA}$	$f_T$	60	–	–	MHz
Feedback Capacitance at $-V_{CE} = 30 \text{ V}$ , $-I_C = 0$ , $f = 1 \text{ MHz}$	$C_{re}$	–	–	1.6	pF
Thermal Resistance Junction to Ambient Air	$R_{thJA}$	–	–	150 <sup>1)</sup>	K/W

<sup>1)</sup> Valid provided that leads are kept at ambient temperature at a distance of 2 mm from case.